



# **Small Signal Fast Switching Diodes**

## **Features**

- · Silicon Epitaxial Planar Diode
- · Low forward voltage drop
- High forward current capability
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



## **Applications**

• High speed switch and general purpose use in computer and industrial applications

#### **Mechanical Data**

Case: DO35 Glass case
Weight: approx. 125 mg
Cathode Band Color: black
Packaging Codes/Options:

TR/10 k per 13" reel (52 mm tape), 50 k/box TAP/10 k per Ammopack (52 mm tape), 50 k/box

#### **Parts Table**

Part	Ordering code	Type Marking	Remarks	
1N4150	1N4150-TR or 1N4150-TAP	1N4150	Tape and Reel/Ammopack	

## **Absolute Maximum Ratings**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Repetitive peak reverse voltage		V <sub>RRM</sub>	50	V	
Reverse voltage		V <sub>R</sub>	50	V	
Peak forward surge current	t <sub>p</sub> = 1 μs	I <sub>FSM</sub>	4	Α	
Average peak forward current		I <sub>FRM</sub>	600	mA	
Forward continuous current		I <sub>F</sub>	300	mA	
Average forward current	V <sub>R</sub> = 0	I <sub>FAV</sub>	150	mA	
Power dissipation	I = 4 mm, T <sub>L</sub> = 45 °C	P <sub>tot</sub>	440	mW	
	$I = 4$ mm, $T_L \le 25$ °C	P <sub>tot</sub>	500	mW	

## **Thermal Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambient air	I = 4 mm, T <sub>L</sub> = constant	R <sub>thJA</sub>	350	K/W
Junction temperature		Tj	175	°C
Storage temperature range		T <sub>stg</sub>	- 65 to + 175	°C

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Rev. 1.7, 16-Feb-07

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## **Electrical Characteristics**

T<sub>amb</sub> = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward voltage	I <sub>F</sub> = 1 mA	V <sub>F</sub>	540		620	mV
	I <sub>F</sub> = 10 mA	V <sub>F</sub>	660		740	mV
	I <sub>F</sub> = 50 mA	V <sub>F</sub>	760		860	mV
	I <sub>F</sub> = 100 mA	V <sub>F</sub>	820		920	mV
	I <sub>F</sub> = 200 mA	V <sub>F</sub>	870		1000	mV
Reverse current	V <sub>R</sub> = 50 V	I <sub>R</sub>			100	nA
	$V_R = 50 \text{ V}, T_j = 150 ^{\circ}\text{C}$	I <sub>R</sub>			100	μΑ
Diode capacitance	$V_R = 0$ , $f = 1$ MHz, $V_{HF} = 50$ mV	C <sub>D</sub>			2.5	pF
Reverse recovery time	$I_F = I_R = (10 \text{ to } 100) \text{ mA}, i_R = 0.1$ $x I_R, R_L = 100 \Omega$	t <sub>rr</sub>			4	ns

**Typical Characteristics** T<sub>amb</sub> = 25 °C, unless otherwise specified

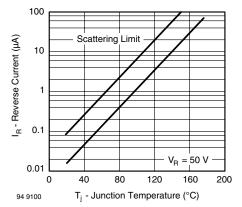


Figure 1. Reverse Current vs. Junction Temperature

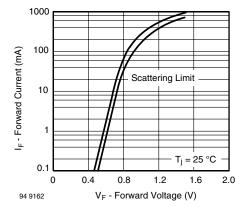
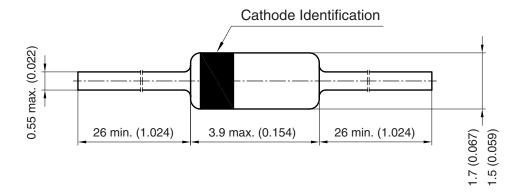


Figure 2. Forward Current vs. Forward Voltage

## Package Dimensions in mm (inches): DO35



Rev. 6 - Date: 29.January 2007 Document no.: 6.560-5004.02-4

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## **Ozone Depleting Substances Policy Statement**

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

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Document Number 85522 www.vishay.com Rev. 1.7, 16-Feb-07



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Document Number: 91000 Revision: 18-Jul-08

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